



Direct imaging antiferromagnetic domains and dynamic switching in thin films by magneto-optical birefringence effect

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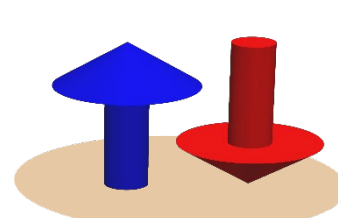
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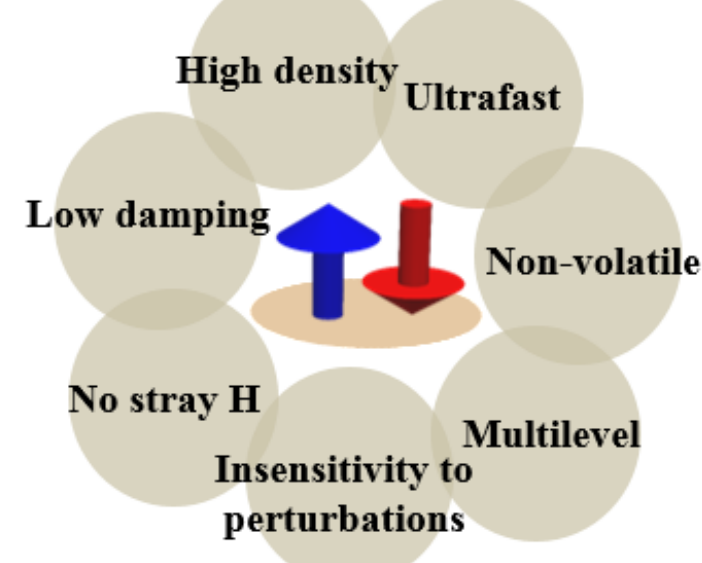
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Introduction

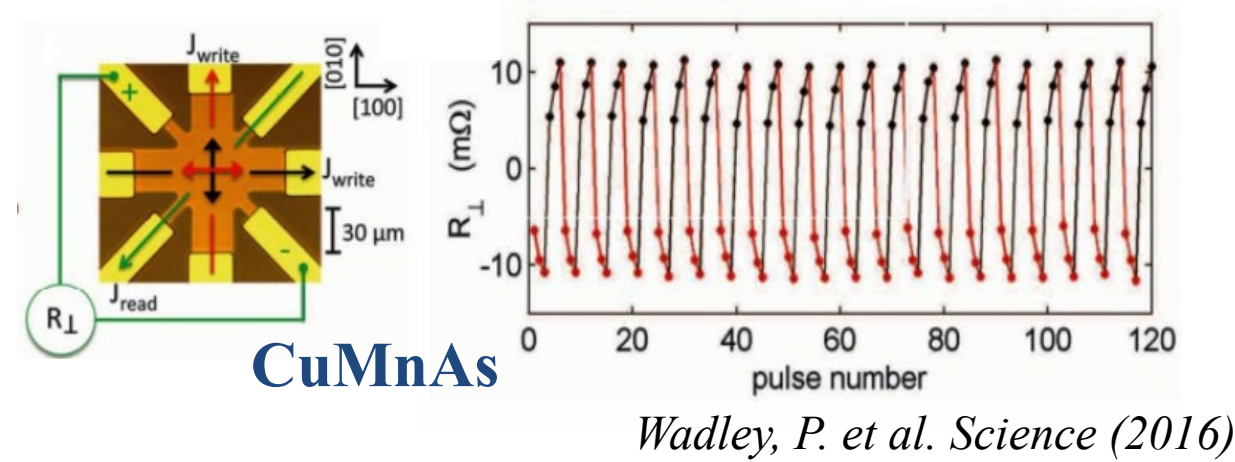


AFM Spintronics

Advantages



In magnetic storage



Microscopic scale?

AFM domain imaging

XMLD-PEEM

Difficult to work with electric or magnetic field

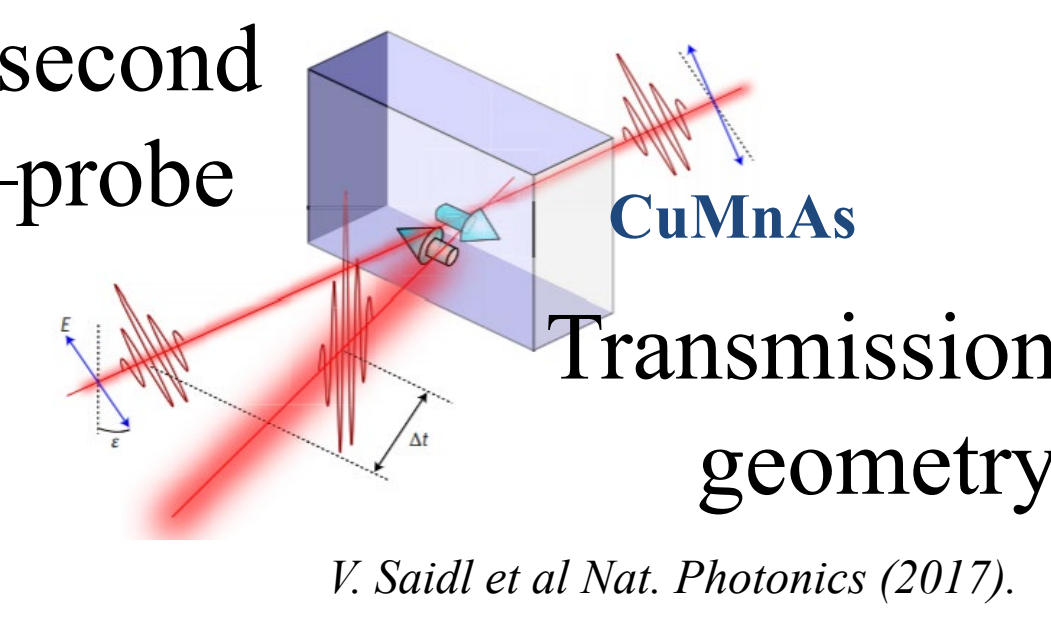
MExFM & NV magnetometry

Require well-ordered, pristine sample surfaces

Optical imaging?

Birefringence effect

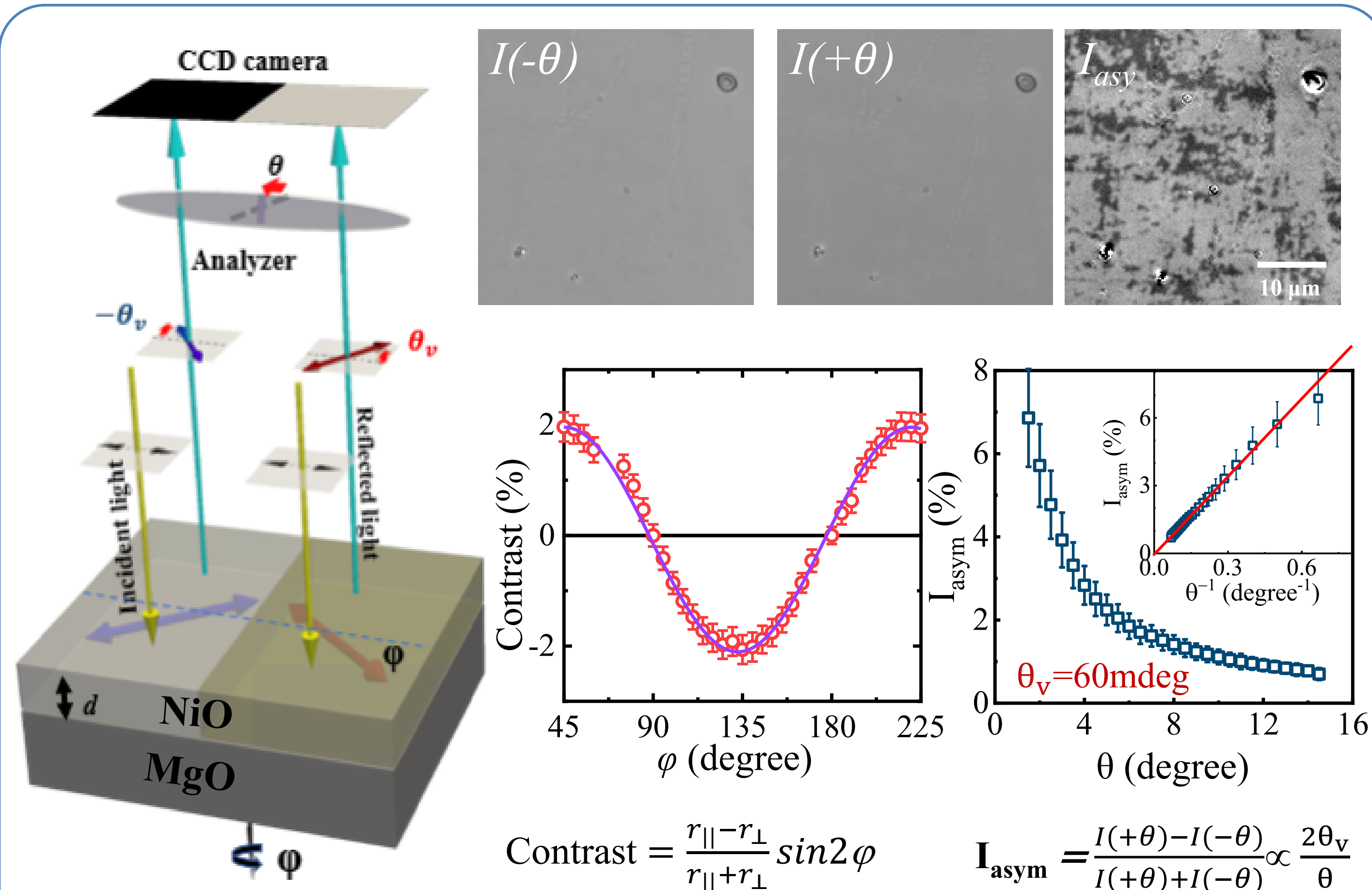
Femtosecond pump-probe



V. Saidl et al Nat. Photonics (2017).

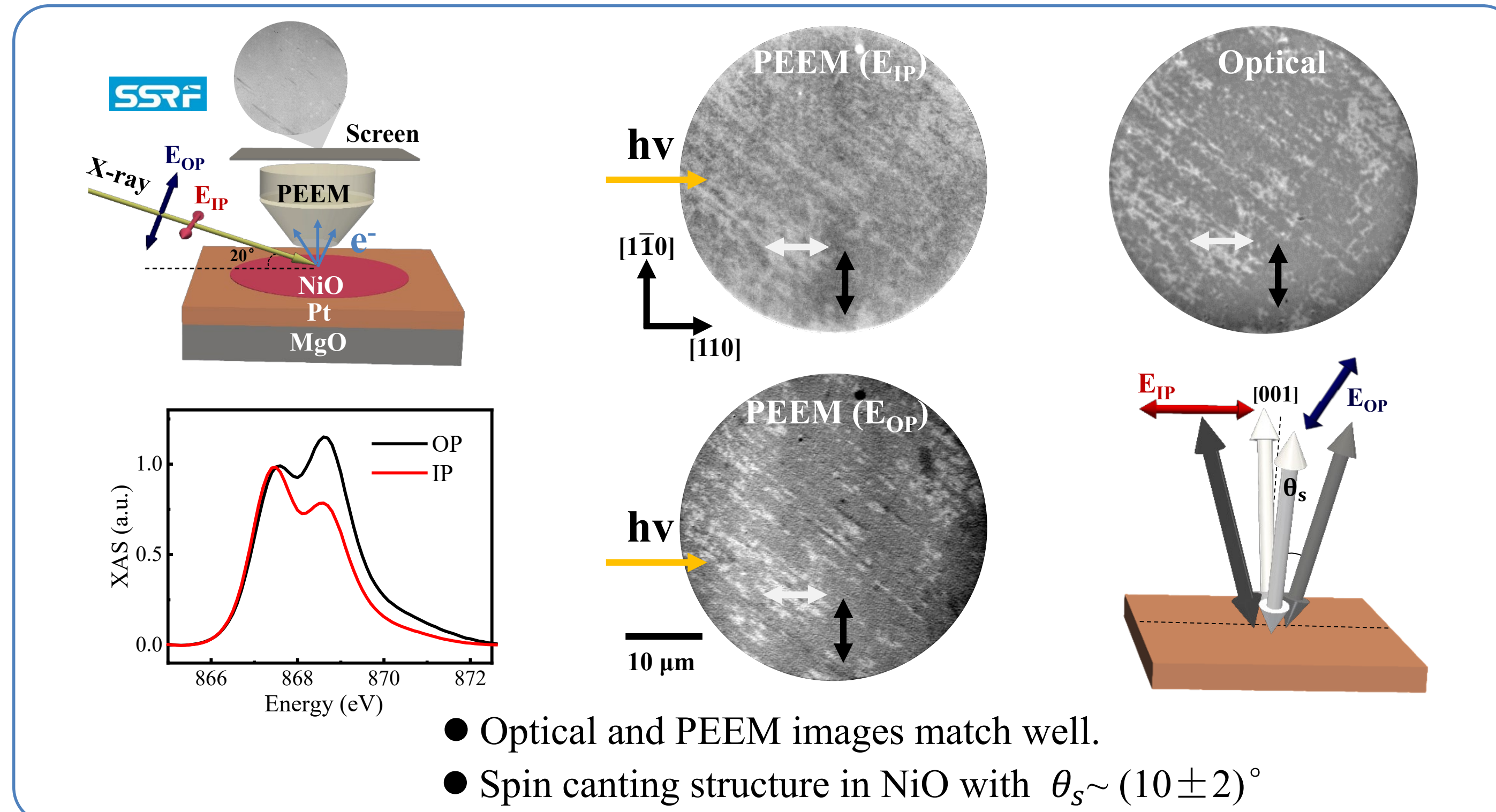
General method?

Methods

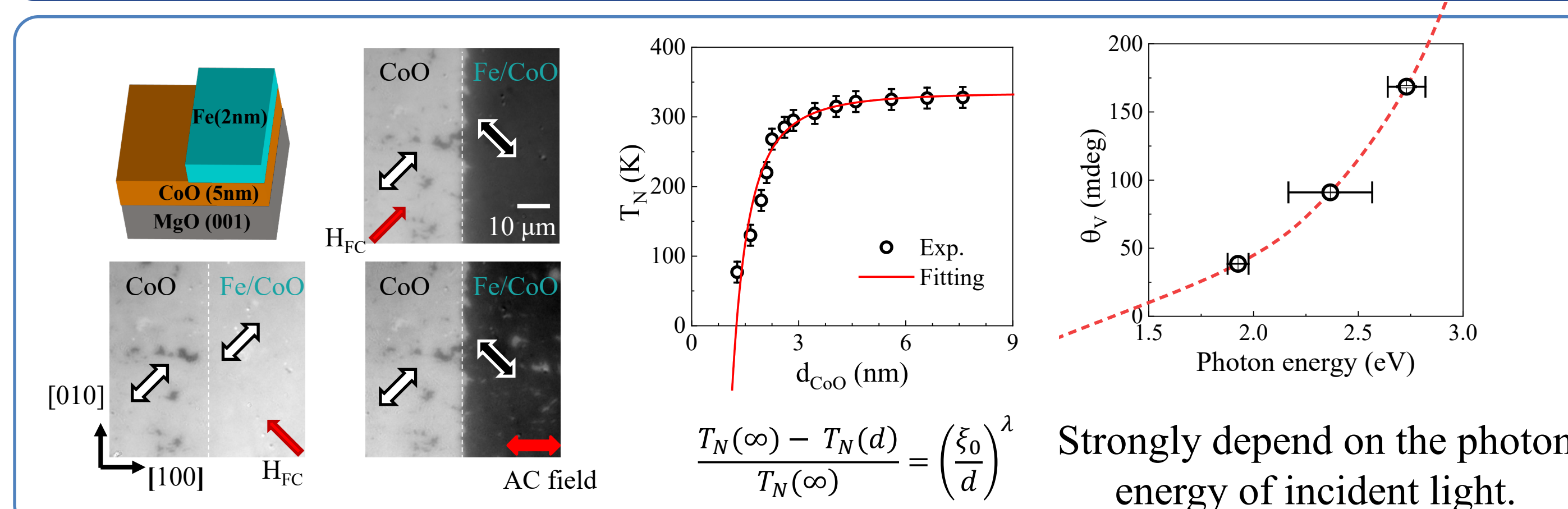


- We can observe the contrasts in NiO induced by the magneto-optical birefringence effect.
- A large polarization rotation angle of 60 mdeg is obtained.

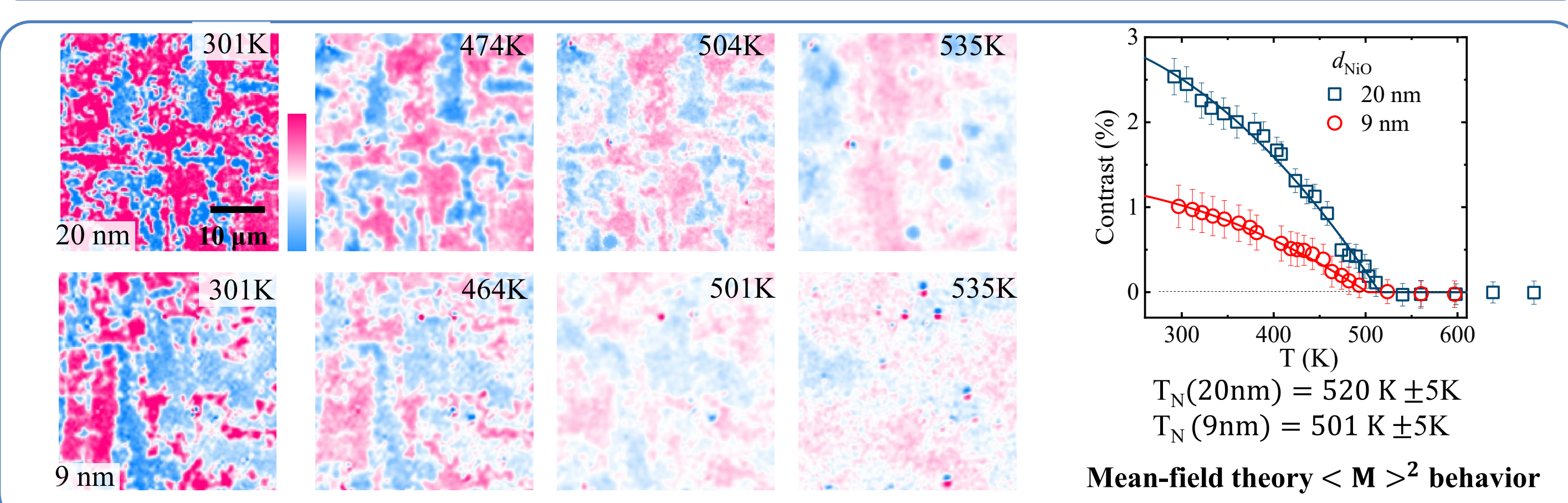
Comparison with PEEM



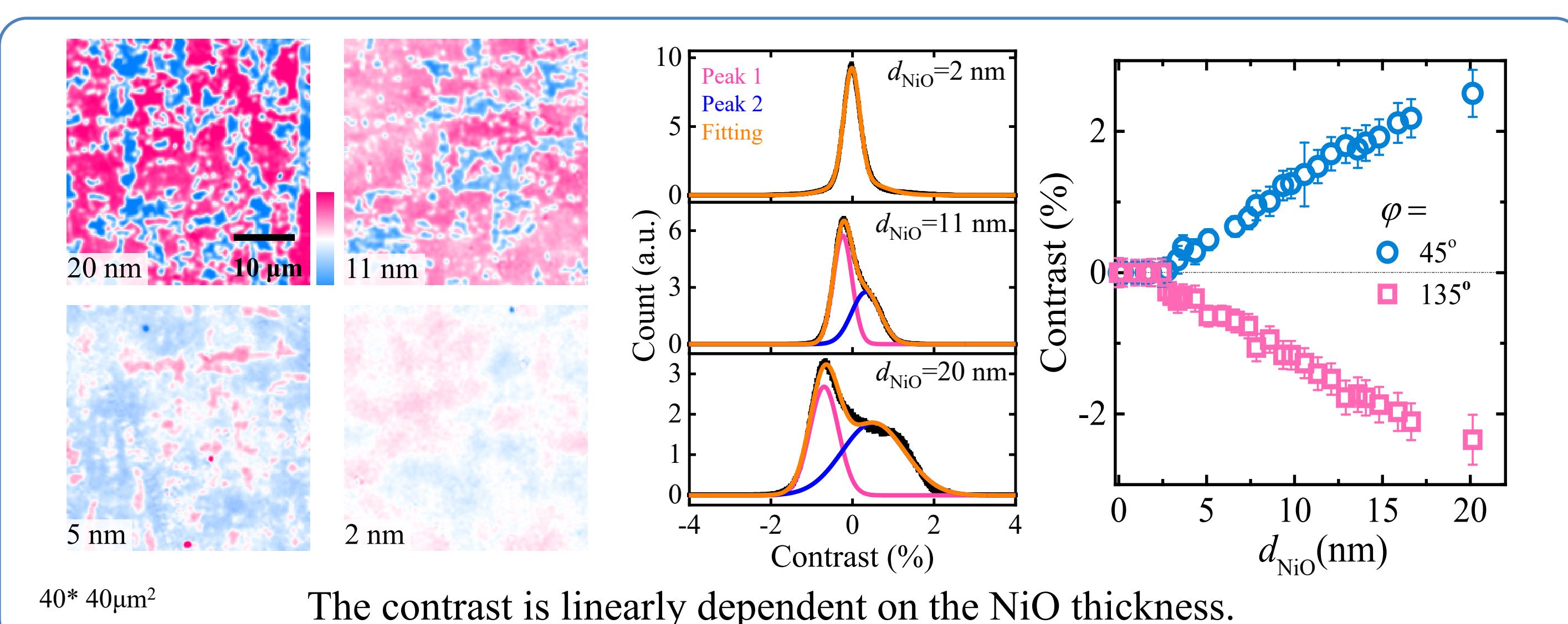
Observe AFM domains in CoO



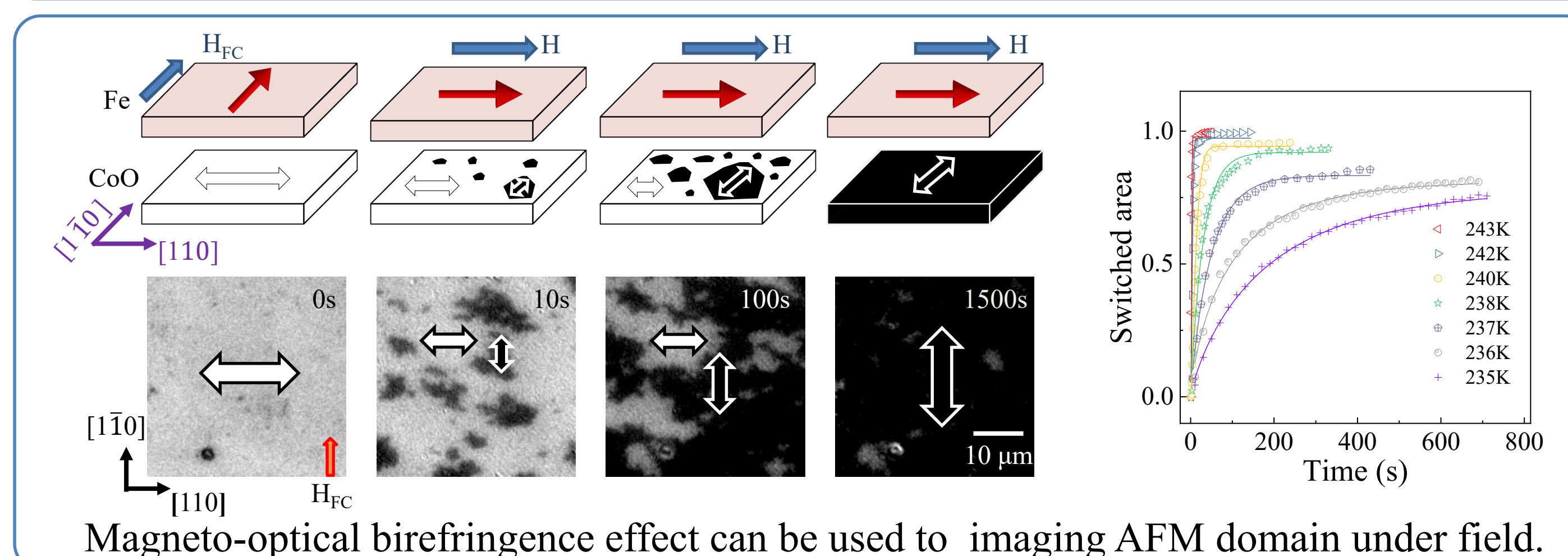
Temperature dependence



Thickness dependence



Dynamic switching in Fe/CoO



Summary

- Optical birefringence effect can be used for imaging AFM domains.
- A new understanding of spin canting structure of NiO grown on MgO.
- Dynamic switching of CoO AFM domain under field can be observed.